



钜地半导体
Tudi Semiconductor

Product Specification

AT24C64D-SSHM-T-TUDI

32K bit (4096*8) 64K bit(8192*8)Two-Serial EEPROM

网址 www.sztdbdt.com

用芯智造 · 卓越品质

**semiconductor device
manufacturer**

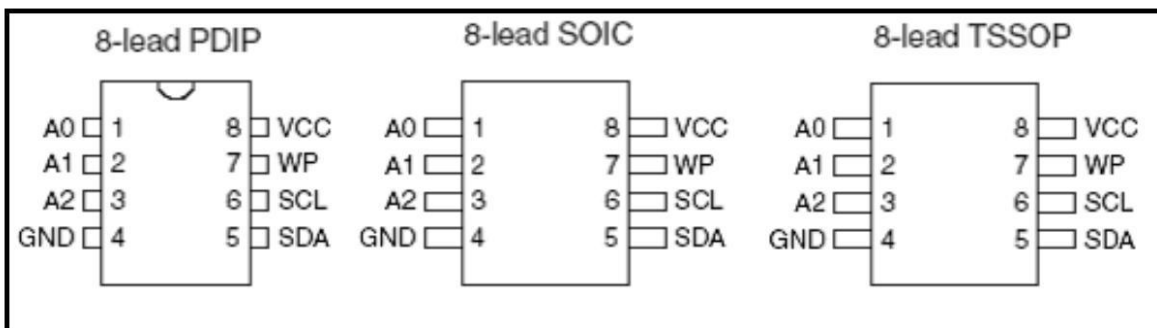
- Design
- research and development
- production
- and sales



■ Features

- Two-wire Serial Interface
- $V_{CC} = 1.8V$ to $5.5V$
- Bi-directional Data Transfer Protocol
- Internally Organized
AT24C32,/CAT24C32 4096 X 8 (32K bits)
AT24C64,/CAT24C64 8192 X 8 (64K bits)
- 400 kHz (1.8V, 2.7V, 5V) Compatibility
- 32-byte Page (32K/64K) Write Modes
- Partial Page Writes Allowed
- Self-timed Write Cycle (5 ms max)
- High-reliability
- 1 Million Write Cycles guaranteed
- Data Retention > 100 Years
- Operating Temperature: $-40^{\circ}C$ to $+85^{\circ}C$
- 8-lead PDIP, 8-lead SOP and 8-lead TSSOP Packages

■ Pin Configuration



■ Description

AT24C32/AT24C64 provides 32768/65536 bits of serial electrically erasable and programmable read-only memory (EEPROM) organized as 4096 words of 8 bits each. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operations are essential. The AT24C32/AT24C64 is available in space-saving 8-lead PDIP, 8-lead SOP, and 8-lead TSSOP packages and is accessed via a two-wire serial interface.



■ Pin Descriptions

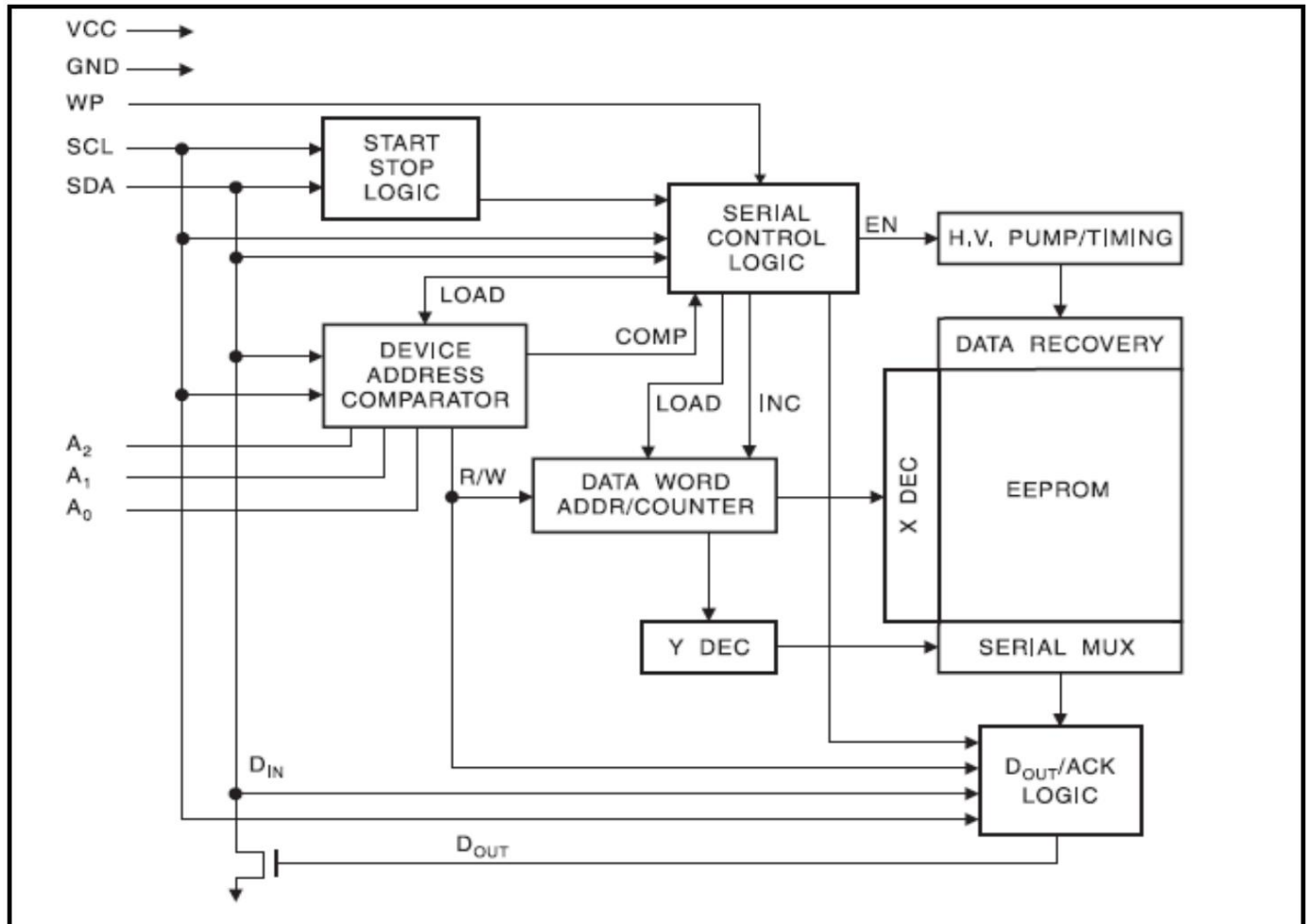
Pin number	Designation	Type	Name and Functions
1 – 3	A0 - A2	I	Address Inputs DEVICE/PAGE ADDRESSES (A2, A1, A0): The A2, A1 and A0 pins are device address inputs that are hardwired or left not connected for hardware compatibility with other 24Cxx devices. When the pins are hardwired, as many as eight 32K/64K devices may be addressed on a single bus system (device addressing is discussed in detail under the Device Addressing section). If the pins are left floating, the A2, A1 and A0 pins will be internally pulled down to GND if the capacitive coupling to the circuit board VCC plane is <3 pF. If coupling is >3 pF, recommends connecting the address pins to GND.
5	SDA	I/O & Open-drain	Serial Data SERIAL DATA (SDA): The SDA pin is bi-directional for serial data transfer. This pin is open-drain driven and may be wire-ORed with any number of other open-drain or open-collector devices.
6	SCL	I	Serial Clock Input SERIAL CLOCK (SCL): The SCL input is used to positive edge clock data into each EEPROM device and negative edge clock data out of each device.
7	WP	I	Write Protect WRITE PROTECT (WP): The write protect input, when connected to GND, allows normal write operations. When WP is connected high to VCC, all write operations to the memory are inhibited. If the pin is left floating, the WP pin will be internally pulled down to GND if the capacitive coupling to the circuit board VCC plane is <3 pF. If coupling is >3 pF, recommends connecting the pin to GND. Switching WP to VCC prior to a write operation creates a software write protect function. The write protection feature is enabled and operates as shown in the following Table 1.
4	GND	P	Ground
8	VCC	P	Power Supply

Table 1: Write Protect

WP Pin Status:	Part of the Array Protected	
	24C32	24C64
At VCC	Full (32K) Array	Full (64K) Array
At GND	Normal Read/Write Operations	



Block Diagram



Functional Description

1. Memory Organization

24C32, 32K SERIAL EEPROM: The 32K is internally organized as 128 pages of 32 bytes each. Random word addressing requires a 12-bit data word address.

24C64, 64K SERIAL EEPROM: The 64K is internally organized as 256 pages of 32 bytes each. Random word addressing requires a 13-bit data word address.

2. Device Operation

CLOCK and DATA TRANSITIONS: The SDA pin is normally pulled high with an external device. Data on the SDA pin may change only during SCL low time periods (see Figure 1). Data changes during SCL high periods will indicate a start or stop condition as defined below.



START CONDITION: A high-to-low transition of SDA with SCL high is a start condition which must precede any other command (see Figure 2).

STOP CONDITION: A low-to-high transition of SDA with SCL high is a stop condition. After a read sequence, the stop command will place the EEPROM in a standby power mode (see Figure 2)

ACKNOWLEDGE: All addresses and data words are serially transmitted to and from the EEPROM in 8-bit words. The EEPROM sends a "0" to acknowledge that it has received each word. This happens during the ninth clock cycle.

STANDBY MODE: The 24C32/24C64 features a low-power standby mode which is enabled: (a) upon power-up and (b) after the receipt of the STOP bit and the completion of any internal operations

MEMORY RESET: After an interruption in protocol, power loss or system reset, any two-wire part can be reset by following these steps:

1. Clock up to 9 cycles.
2. Look for SDA high in each cycle while SCL is high.
3. Create a start condition.

Figure 1. Data Validity

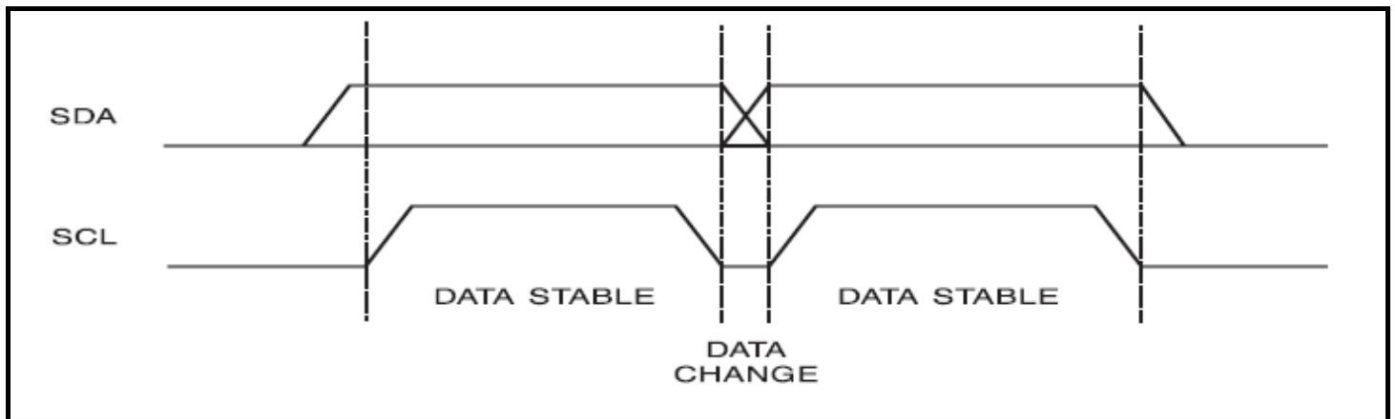
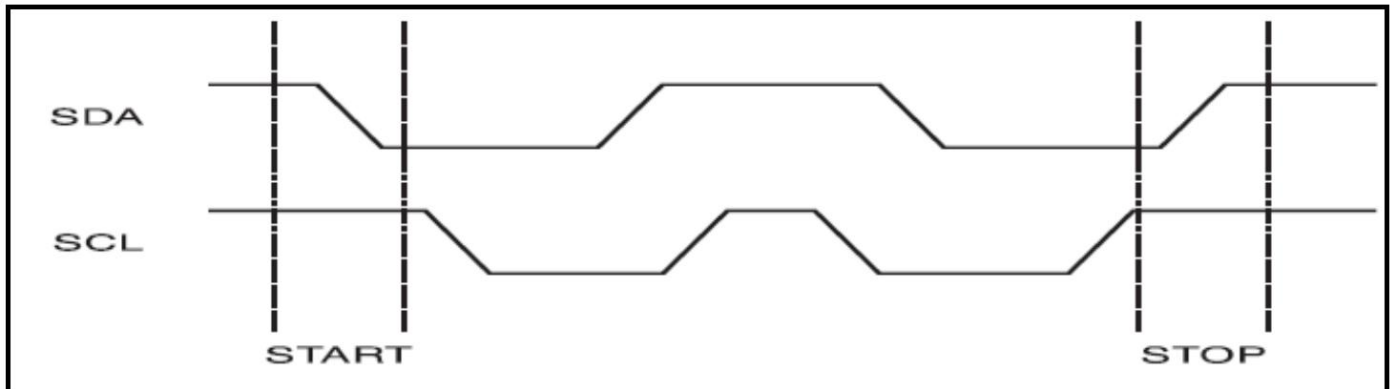
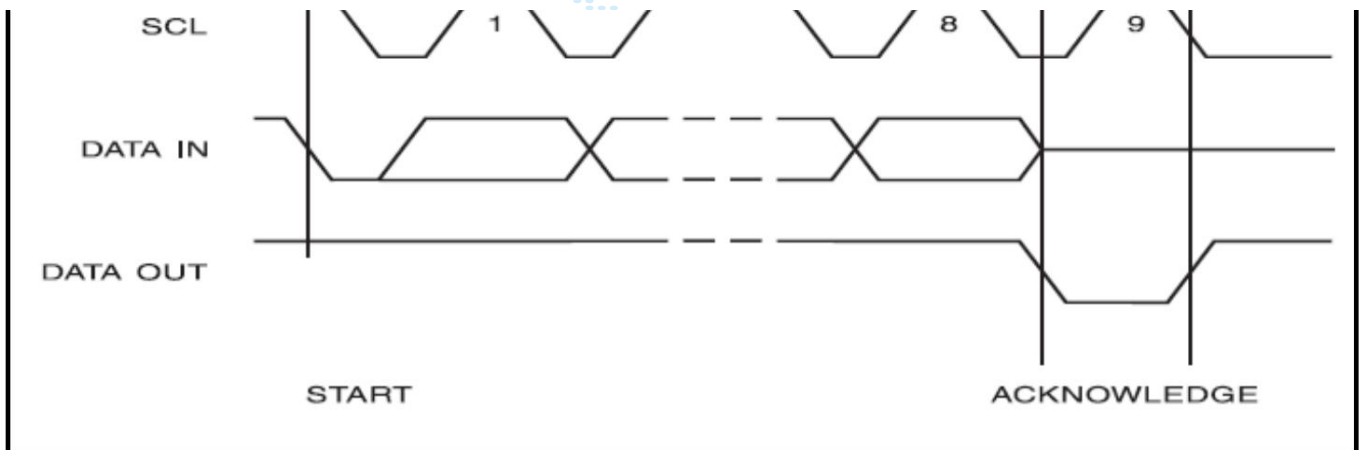


Figure 2. Start and Stop Definition





3. Device Addressing

The 32K/64K EEPROM devices all require an 8-bit device address word following a start condition to enable the chip for a read or write operation (see Figure 4).

The device address word consists of a mandatory “1”, “0” sequence for the first four most significant bits as shown. This is common to all the Serial EEPROM devices.

The 32K/64K uses the three device address bits A2, A1, A0 to allow as many as eight devices on the same bus. These bits must compare to their corresponding hardwired input pins. The A2, A1, and A0 pins use an internal proprietary circuit that biases them to a logic low condition if the pins are allowed to float.

The eighth bit of the device address is the read/write operation select bit. A read operation is initiated if this bit is high and a write operation is initiated if this bit is low.

Upon a compare of the device address, the EEPROM will output a “0”. If a compare is not made, the chip will return to a standby state.

NOISE PROTECTION: Special internal circuitry placed on the SDA and SCL pins prevent small noise spikes from activating the device.

DATA SECURITY: The 24C32/24C64 has a hardware data protection scheme that allows the user to write protect the entire memory when the WP pin is at VCC.

4. Write Operations

BYTE WRITE: A write operation requires an 8-bit data word address following the device address word and acknowledgment. Upon receipt of this address, the EEPROM will again respond with a “0” and then clock in the first 8-bit data word. Following receipt of the 8-bit data word, the EEPROM will output a “0” and the addressing device, such as a microcontroller, must terminate the write sequence with a stop condition. At this time the EEPROM enters an internally timed write cycle, t_{WR} , to the nonvolatile memory. All inputs are disabled during this write cycle and the EEPROM will not respond until the write is complete (see Figure 5).



PAGE WRITE: The 32K/64K devices are capable of 32-byte page writes.

A page write is initiated the same as a byte write, but the microcontroller does not send a stop condition after the first data word is clocked in. Instead, after the EEPROM acknowledges receipt of the first data word, the microcontroller can transmit up to 31 more data words. The EEPROM will respond with a “0” after each data word received. The microcontroller must terminate the page write sequence with a stop condition (see Figure 6).

The data word address lower five (32K/64K) bits are internally incremented following the receipt of each data word. The higher data word address bits are not incremented, retaining the memory page row location. When the word address, internally generated, reaches the page boundary, the following byte is placed at the beginning of the same page. If more than 32 data words are transmitted to the EEPROM, the data word address will “roll over” and previous data will be overwritten.

ACKNOWLEDGE POLLING: Once the internally timed write cycle has started and the EEPROM inputs are disabled, acknowledge polling can be initiated. This involves sending a start condition followed by the device address word. The read/write bit is representative of the operation desired. Only if the internal write cycle has completed will the EEPROM respond with a “0”, allowing the read or write sequence to continue.

5. Read Operations

Read operations are initiated the same way as write operations with the exception that the read/write select bit in the device address word is set to “1”. There are three read operations: current address read, random address read and sequential read.

CURRENT ADDRESS READ: The internal data word address counter maintains the last address accessed during the last read or write operation, incremented by one. This address stays valid between operations as long as the chip power is maintained. The address “roll over” during read is from the last byte of the last memory page to the first byte of the first page. The address “roll over” during write is from the last byte of the current page to the first byte of the same page.

Once the device address with the read/write select bit set to “1” is clocked in and acknowledged by the EEPROM, the current address data word is serially clocked out. The microcontroller does not respond with an input “0” but does generate a following stop condition (see Figure 7).

RANDOM READ: A random read requires a “dummy” byte write sequence to load in the data word address. Once the device address word and data word address are clocked in and acknowledged by the EEPROM, the microcontroller must generate another start condition. The microcontroller now initiates a current address read by sending a device address with the read/write select bit high. The EEPROM acknowledges the device address and serially clocks out the data word. The microcontroller does not respond with a “0” but does generate a following stop condition (see Figure 8).

SEQUENTIAL READ: Sequential reads are initiated by either a current address read or a random address read. After the microcontroller receives a data word, it responds with an acknowledge. As long as the EEPROM receives an acknowledge, it will continue to increment the data word address and serially clock out sequential data words. When the memory address limit is reached, the data word address will “roll over” and the sequential read will continue. The sequential read operation is terminated when the microcontroller does not respond with a “0” but does generate a following stop condition (see Figure 9)

Figure 4. Device Address

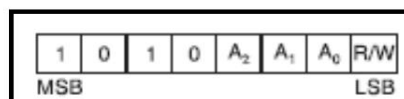




Figure 5. Byte Write

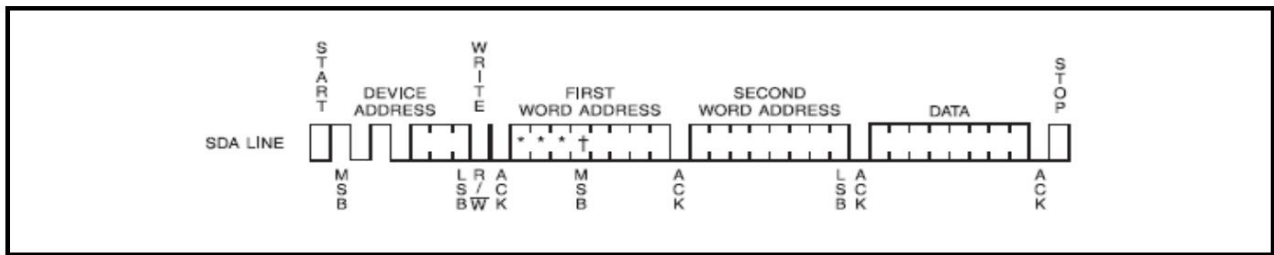


Figure 6. Page Write

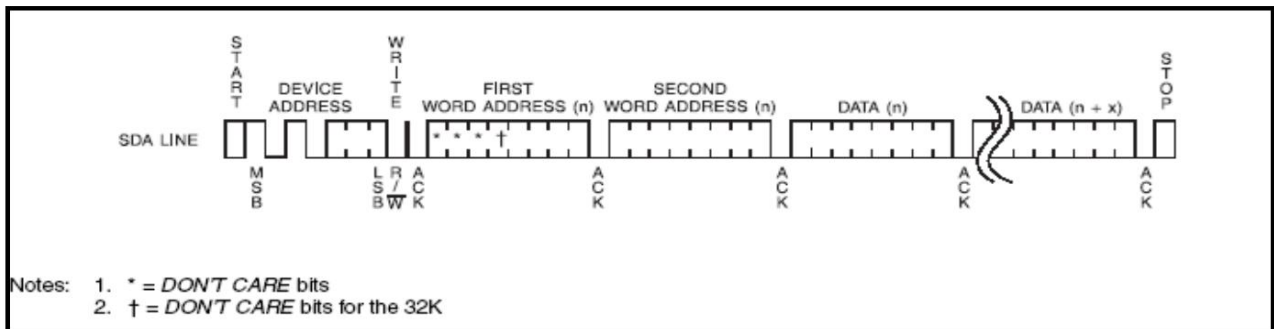


Figure 7. Current Address Read

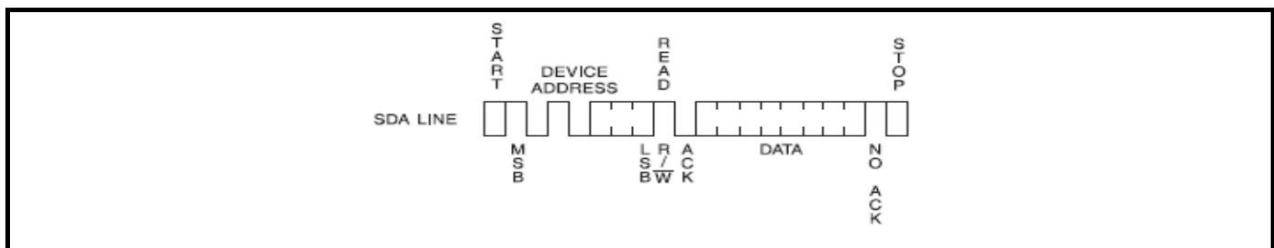


Figure 8. Random Read

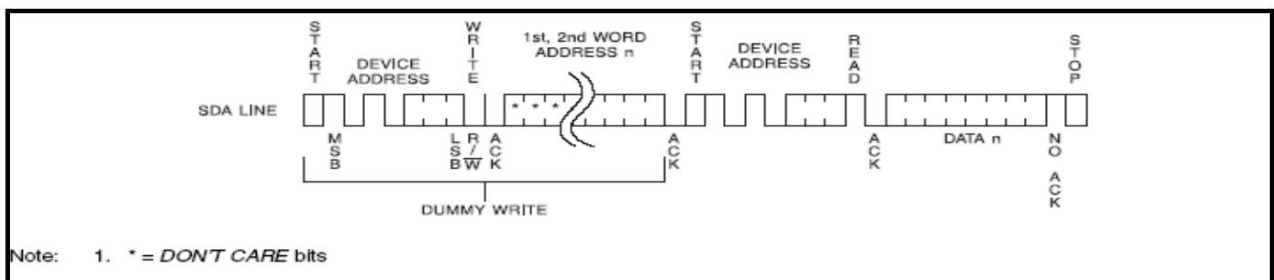
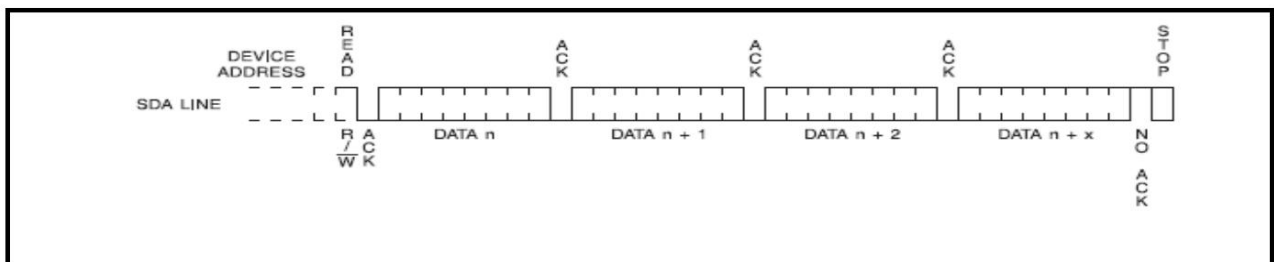


Figure 9. Sequential Read





■ Electrical Characteristics

● Absolute Maximum Stress Ratings

DC Supply Voltage	-0.3V to +6.5V
Input / Output Voltage	GND-0.3V to $V_{CC}+0.3V$
Operating Ambient Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

● Comments

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to this device. These are stress ratings only. Functional operation of this device at these or any other conditions above those indicated in the operational sections of this specification is not implied or intended. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

■ DC Electrical Characteristics

- Applicable over recommended operating range from: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = +1.8\text{V}$ to $+5.5\text{V}$ (unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Supply Voltage	V_{CC}	1.8	-	5.5	V	
Supply Current $V_{CC} = 5.0\text{V}$	I_{CC1}	-	0.4	1.0	mA	READ at 100 kHz
Supply Current $V_{CC} = 5.0\text{V}$	I_{CC2}	-	2.0	3.0	mA	WRITE at 100 kHz
Standby Current	I_{SB}	-	-	1.0	μA	$V_{IN} = V_{CC}$ or GND
Input Leakage Current	I_{LI}	-	-	3.0	μA	$V_{IN} = V_{CC}$ or GND
Output Leakage Current	I_{LO}	-	0.05	3.0	μA	$V_{OUT} = V_{CC}$ or GND
Input Low Level	V_{IL}	-0.6	-	$V_{CC} \times 0.3$	V	
Input High Level	V_{IH}	$V_{CC} \times 0.7$	-	$V_{CC} + 0.5$	V	
Output Low Level $V_{CC} = 5.0\text{V}$	V_{OL3}	-	-	0.4	V	$I_{OL} = 3.0\text{ mA}$
Output Low Level $V_{CC} = 3.0\text{V}$	V_{OL2}	-	-	0.4	V	$I_{OL} = 2.1\text{ mA}$
Output Low Level $V_{CC} = 1.8\text{V}$	V_{OL1}	-	-	0.2	V	$I_{OL} = 0.15\text{ mA}$

■ Pin Capacitance

- Applicable over recommended operating range from $T_A = 25^{\circ}\text{C}$, $f = 1.0\text{ MHz}$, $V_{CC} = +1.8\text{V}$

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Input/Output Capacitance (SDA)	C_{IO}	-	-	8	pF	$V_{IO} = 0\text{V}$
Input Capacitance (A0, A1, A2, SCL)	C_{IN}	-	-	6	pF	$V_{IN} = 0\text{V}$



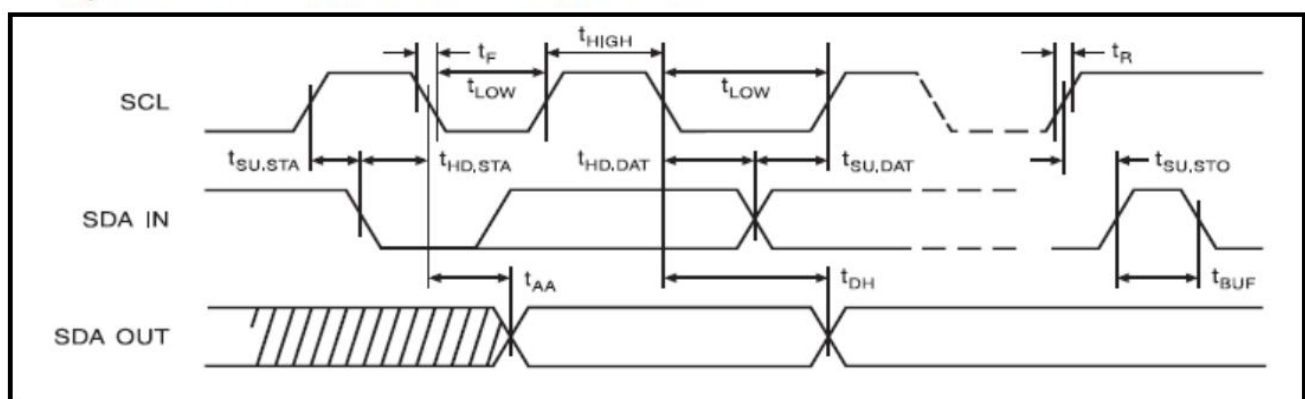
AC Electrical Characteristics

Applicable over recommended operating range from $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = +1.8\text{V}$ to $+5.5\text{V}$, $C_L = 1$ TTL Gate and 100 pF (unless otherwise noted)

Parameter	Symbol	1.8, 2.7, 5.0-volt			Units
		Min.	Typ.	Max.	
Clock Frequency, SCL	f_{SCL}	-	-	400	kHz
Clock Pulse Width Low	t_{LOW}	1.2	-	-	μs
Clock Pulse Width High	t_{HIGH}	0.6	-	-	μs
Noise Suppression Time	t_i	-	-	50	ns
Clock Low to Data Out Valid	t_{AA}	0.1	-	0.9	μs
Time the bus must be free before a new transmission can start	t_{BUF}	1.2	-	-	μs
Start Hold Time	$t_{\text{HD,STA}}$	0.6	-	-	μs
Start Setup Time	$t_{\text{SU,STA}}$	0.6	-	-	μs
Data In Hold Time	$t_{\text{HD,DAT}}$	0	-	-	μs
Data In Setup Time	$t_{\text{SU,DAT}}$	100	-	-	ns
Inputs Rise Time	t_R	-	-	0.3	μs
Inputs Fall Time	t_F	-	-	300	ns
Stop Setup Time	$t_{\text{SU,STO}}$	0.6	-	-	μs
Data Out Hold Time	t_{DH}	50	-	-	ns
Write Cycle Time	t_{WR}	-	-	5	ms
5.0V, 25°C , Byte Mode	Endurance	1M	-	-	Write Cycles

Bus Timing

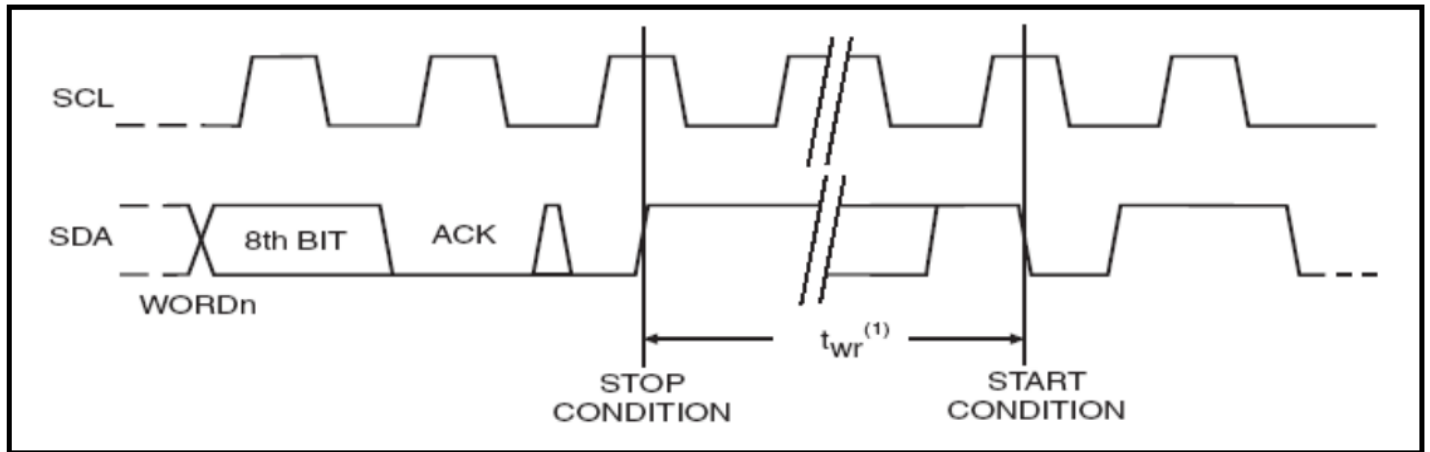
Figure 10. SCL: Serial Clock, SDA: Serial Data I/O





Write Cycle Timing

Figure 11. SCL: Serial Clock, SDA: Serial Data I/O



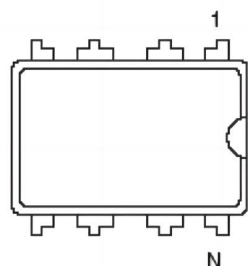
Note:

1. The write cycle time t_{WR} is the time from a valid stop condition of a write sequence to the end of the internal clear/write cycle.

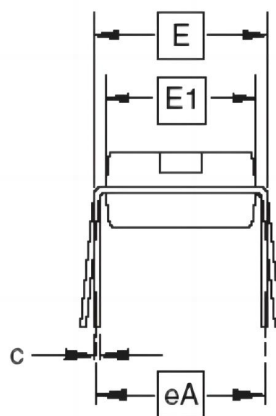


Package Information

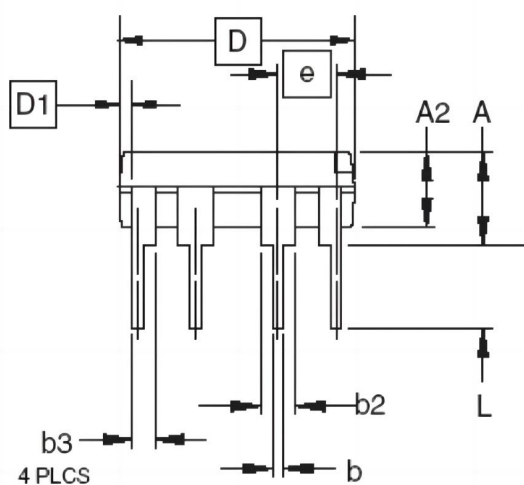
PDIP Outline Dimensions



Top View



End View



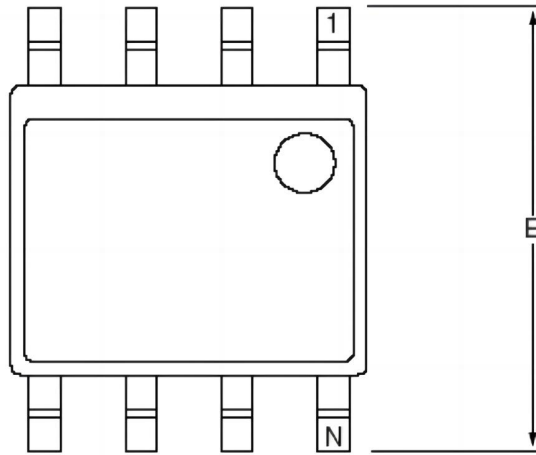
Side View

COMMON DIMENSIONS
(Unit of Measure = inches)

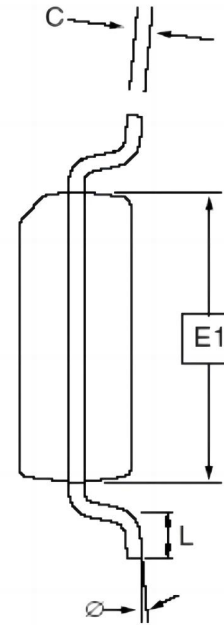
SYMBOL	MIN	NOM	MAX	NOTE
A			0.210	2
A2	0.115	0.130	0.195	
b	0.014	0.018	0.022	5
b2	0.045	0.060	0.070	6
b3	0.030	0.039	0.045	6
c	0.008	0.010	0.014	
D	0.355	0.365	0.400	3
D1	0.005			3
E	0.300	0.310	0.325	4
E1	0.240	0.250	0.280	3
e	0.100 BSC			
eA	0.300 BSC			4
L	0.115	0.130	0.150	2



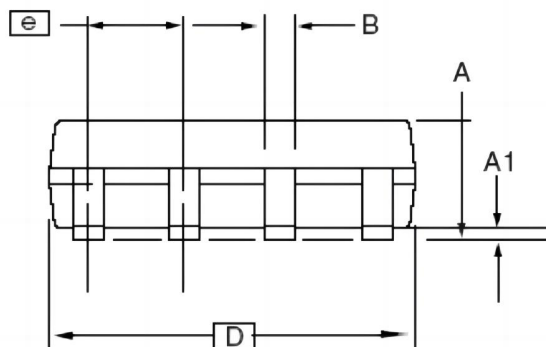
JEDEC SOIC



Top View



End View



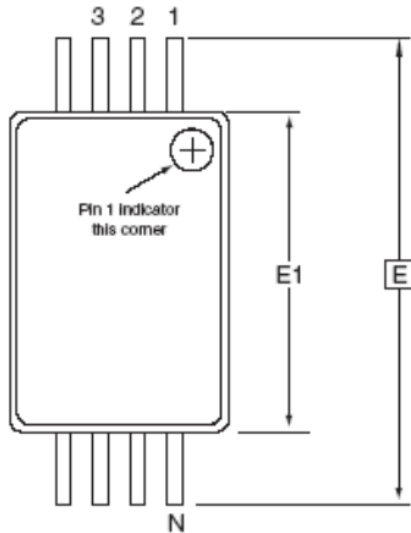
Side View

COMMON DIMENSIONS
(Unit of Measure = mm)

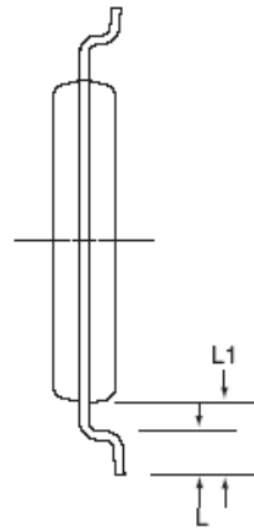
SYMBOL	MIN	NOM	MAX	NOTE
A	1.35	—	1.75	
A1	0.10	—	0.25	
b	0.31	—	0.51	
C	0.17	—	0.25	
D	4.80	—	5.00	
E1	3.81	—	3.99	
E	5.79	—	6.20	
e	1.27 BSC			
L	0.40	—	1.27	
∅	0°	—	8°	



TSSOP



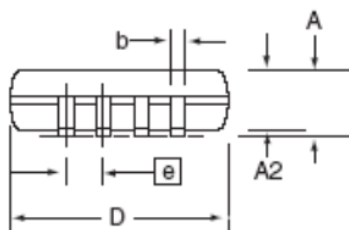
Top View



End View

COMMON DIMENSIONS
(Unit of Measure = mm)

SYMBOL	MIN	NOM	MAX	NOTE
D	2.90	3.00	3.10	2, 5
E	6.40 BSC			
E1	4.30	4.40	4.50	3, 5
A	—	—	1.20	
A2	0.80	1.00	1.05	
b	0.19	—	0.30	4
e	0.65 BSC			
L	0.45	0.60	0.75	
L1	1.00 REF			



Side View

Ordering information

Order Number	Package	Package Quantity	Marking On The park
AT24C64D-SSHM-T-TUDI	SOP8	Tape,Reel,2500	64DM



Important statement:

- TUDI Semiconductor reserves the right to modify the product manual without prior notice! Before placing an order, customers need to confirm whether the obtained information is the latest version and verify the completeness of the relevant information.
- Any semi-guide product is subject to failure or malfunction under specified conditions. It is the buyer's responsibility to comply with safety standards when using TUDI Semiconductor products for system design and whole machine manufacturing. And take the appropriate safety measures to avoid the potential in the risk of loss of personal injury or loss of property situation!
- TUDI Semiconductor products have not been licensed for life support, military, and aerospace applications, and therefore TUDI Semiconductor is not responsible for any consequences arising from the use of this product in these areas.
- If any or all TUDI Semiconductor products (including technical data, services) described or contained in this document are subject to any applicable local export control laws and regulations, they may not be exported without an export license from the relevant authorities in accordance with such laws.
- The specifications of any and all TUDI Semiconductor products described or contained in this document specify the performance, characteristics, and functionality of said products in their standalone state, but do not guarantee the performance, characteristics, and functionality of said products installed in Customer's products or equipment. In order to verify symptoms and conditions that cannot be evaluated in a standalone device, the Customer should ultimately evaluate and test the device installed in the Customer's product device.
- TUDI Semiconductor documentation is only allowed to be copied without any alteration of the content and with the relevant authorization. TUDI Semiconductor assumes no responsibility or liability for altered documents.
- TUDI Semiconductor is committed to becoming the preferred semiconductor brand for customers, and TUDI Semiconductor will strive to provide customers with better performance and better quality products.